FILE 'HOME' ENTERED AT 17:07:05 ON 30 AUG 2005

=> FIL STNGUIDE

COST IN U.S. DOLLARS SINCE FILE TOTAL ENTRY SESSION

FULL ESTIMATED COST 0.21 0.21

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AND TECHNOLOGY CORPORATION, AND FACHINFORMATIONSZENTRUM KARLSRUHE

FILE CONTAINS CURRENT INFORMATION.

LAST RELOADED: Aug 26, 2005 (20050826/UP).

=> file pnttext

COST IN U.S. DOLLARS SINCE FILE TOTAL ENTRY SESSION

FULL ESTIMATED COST 0.06 0.27

FILE 'EPFULL' ENTERED AT 17:07:20 ON 30 AUG 2005

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FILE 'USPATFULL' ENTERED AT 17:07:20 ON 30 AUG 2005
CA INDEXING COPYRIGHT (C) 2005 AMERICAN CHEMICAL SOCIETY (ACS)

FILE 'USPAT2' ENTERED AT 17:07:20 ON 30 AUG 2005
CA INDEXING COPYRIGHT (C) 2005 AMERICAN CHEMICAL SOCIETY (ACS)

=> s polyoxymethylene and formaldehyde and catalyst#

6 FILES SEARCHED...

L1 2336 POLYOXYMETHYLENE AND FORMALDEHYDE AND CATALYST#

=> s l1 and cyclooctadiene

L2 28 L1 AND CYCLOOCTADIENE

=> s 12 and tetrahydrofuran

L3 11 L2 AND TETRAHYDROFURAN

=> s 13 and ligand#

L4 6 L3 AND LIGAND#

=> s 13 and (pentamethylcyclopentadienyl or pentamethyl cyclopentadienyl)

L5 1 L3 AND (PENTAMETHYLCYCLOPENTADIENYL OR PENTAMETHYL CYCLOPENTADIENYL)

=> d

AN

L5 ANSWER 1 OF 1 USPATFULL on STN

2005:203498 USPATFULL

TI Production of polyoxymethylene and suitable catalysts

IN Gortz, Hans-Helmut, Freinshein, GERMANY, FEDERAL REPUBLIC OF

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Luinstra, Gerrit, Mannheim, GERMANY, FEDERAL REPUBLIC OF
       Forster, Monika, Muhltal, GERMANY, FEDERAL REPUBLIC OF
       Baumann, Andreas, Nurtingen, GERMANY, FEDERAL REPUBLIC OF
       Lindner, Ekkehard, Tubingen, GERMANY, FEDERAL REPUBLIC OF
PΙ
       US 2005176924
                          A1
                               20050811
ΑI
       US 2003-510475
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                               20030410 (10)
       WO 2003-EP3746
                               20030410
PRAI
       DE 2003-102159785
                           20020411
DT
       Utility
FS
       APPLICATION
LN.CNT 618
INCL
       INCLM: 528/425.000
NCL
       NCLM: 528/425.000
IC
       [7]
       ICM: C08G065-34
CAS INDEXING IS AVAILABLE FOR THIS PATENT.
=> d l3 1-11
L3
       ANSWER 1 OF 11
                         EPFULL
                                  COPYRIGHT 2005 EPO/FIZ KA on STN
       2005:1622
                     EPFULL EDP 20050727 ED 20050727 UP 20050727
AN
       DUPD 20050727 DUPW 200530
TTEN
       Lithographic printing plate precursor and lithographic printing method.
TIFR
       Precurseur de plaque d'impression lithographique et methode pour
       l'impression lithographique.
TIDE
       Flachdruckplattenvorlaeufer und Flachdruckverfahren.
IN
       Inno, Toshifumi, Fuji Photo Film Co., Ltd., 4000, Kawashiri,
       Yoshida-cho, Haibara-gun, Shizuoka, JP;
       Oshima, Yasuhito, Fuji Photo Film Co., Ltd., 4000, Kawashiri,
       Yoshida-cho, Haibara-gun, Shizuoka, JP;
       Kakino, Ryuki, Fuji Photo Film Co., Ltd., 4000, Kawashiri,
       Yoshida-cho, Haibara-gun, Shizuoka, JP
PA
       Fuji Photo Film Co., Ltd., 210, Nakanuma, Minami-Ashigara-shi,
       Kanagawa, JP
PAN
       2602262
       HOFFMANN - EITLE, Patent- und Rechtsanwaelte Arabellastrasse 4,
AG
       Muenchen, DE
AGN
       101511
LAF
       English
LA
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LAP
       English
       German; English; French
TL
DT
       Patent
PIT
       EPA2 Application published without search report
PΤ
       EP 1557262
                            A2 20050727
DS
       AT BE BG CH CY CZ DE DK EE ES FI FR GB GR HU IE IS IT LI LT LU MC NL PL
       PT RO SE SI SK TR
AΙ
       EP 2005-1195
                            A 20050121
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       JP 2004-15766
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                               20040123
       JP 2004-86566
                            A 20040324
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       B41C001-10
ICS
       B41M005-30; B41M005-28
                     EPFULL EDP 20050727 ED 20050810 UP 20050810
       2005:1622
AN
       DUPD 20050810 DUPW 200532
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TIEN
       Precurseur de plaque d'impression lithographique et methode pour
TIFR
       l'impression lithographique.
TIDE
       Flachdruckplattenvorlaeufer und Flachdruckverfahren.
IN
       Inno, Toshifumi, Fuji Photo Film Co., Ltd., 4000, Kawashiri,
       Yoshida-cho, Haibara-gun, Shizuoka, JP;
       Oshima, Yasuhito, Fuji Photo Film Co., Ltd., 4000, Kawashiri,
       Yoshida-cho, Haibara-gun, Shizuoka, JP;
       Kakino, Ryuki, Fuji Photo Film Co., Ltd., 4000, Kawashiri,
       Yoshida-cho, Haibara-gun, Shizuoka, JP
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Fuji Photo Film Co., Ltd., 210, Nakanuma, Minami-Ashigara-shi,
PA
       Kanagawa, JP
PAN
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AG
       HOFFMANN - EITLE, Patent- und Rechtsanwaelte Arabellastrasse 4, 81925
       Muenchen, DE
AGN
       101511
LAF
       English
LΑ
       English
LAP
       English
       German; English; French
TL
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PIT
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                            A3 20050810
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DS
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ICS
       B41M005-30; B41M005-28
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ΑN
       1995:38854
                     EPFULL UP 20050511
       DUPD 20050511 DUPW 200519
TIEN
       NOVEL RESIN COMPOSITION.
TIFR
       NOUVELLE COMPOSITION DE RESINE.
TIDE
       NEUE HARZZUSAMMENSETZUNG.
IN
       NATORI, Itaru, Room No. 405, Sukaihaimu, 817-3, Tookaichibamachi,
       Midori-ku, Yokohama-shi, Kanagawa-ken 227, JP;
       IMAIZUMI, Kimio, Room No. 208, Kanetsuka Mansion, 280-3, Noshio
       5-chome, Kiyose-shi, Tokyo 204, JP;
       KATO, Kiyoo, Room 101, Domiiru-Kaishima 3-18-15, Shimokodanaka,
       Nakahara-ku, Kawasaki-shi, Kanagawa-ken 211, JP
       Asahi Kasei Kabushiki Kaisha, 2-6, Dojimahama 1-chome, Kita-ku,
PA
       Osaka-shi, Osaka, JP
       219577
PAN
       Blake, John Henry Francis, et al, Brookes Batchellor 102-108 Clerkenwell
AG
       Road, London EC1M 5SA, GB
AGN
       28375
LAF
       Japanese
LΑ
       English
LAP
       English
TL
       German; English; French
DT
PIT
       EPA1 Application published with search report
PΙ
       EP 743341
                            A1 19961120
       WO 9521217
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DS
       DE FR GB
ΑI
       EP 1995-900930
                            A 19941121
       WO 1994-JP1970
                            A 19941121
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       JP 1994-10567
                            A 19940201
IC.VER 7
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       C08L045-00
L3
       ANSWER 3 OF 11
                         GBFULL
                                  COPYRIGHT 2005 Univentio on STN
AN
       2311071 GBFULL ED 20041103
TI
       Curable resin and composition
IN
       NATORI, ITARU; WATANABE, TOMONARI
PA
       ASAHI KASEI KOGYO KABUSHIKI KAISHA
PA.CNY JP
DT
       Patent
PIT
       GBA Application published
PΙ
       GB 2311071
                            A 19970917
ΑI
       GB 1997-10454
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PRAI
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       WO 1995-JP2375
                            A 19941121
       JP 1994-286899
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L3
       ANSWER 4 OF 11
       2004072168 PCTFULL ED 20040901 EW 200435
AN
TIEN
       RESIN COMPOSITIONS
TIFR
       COMPOSITIONS DE RESINE
IN
       SCHMIDT, Hans-Werner, Lisztstrasse 26, 95444 Bayreuth, DE [DE, DE];
       BLOMENHOFER, Markus, Kanzleistrasse 54, 96328 Kueps-Johannisthal, DE
       [DE, DE];
       STOLL, Klaus, Am Sonnenrain 18, 79589 Binzen, DE [DE, DE];
       MEIER, Hans-Rudolf, Muespacherstrasse 74, CH-4055 Basel, CH [CH, CH]
       CIBA SPECIALTY CHEMICALS HOLDING INC., Klybeckstrasse 141, CH-4057
PA
       Basel, CH [CH, CH], for all designates States except US;
       SCHMIDT, Hans-Werner, Lisztstrasse 26, 95444 Bayreuth, DE [DE, DE], for
       US only;
       BLOMENHOFER, Markus, Kanzleistrasse 54, 96328 Kueps-Johannisthal, DE
       [DE, DE], for US only;
       STOLL, Klaus, Am Sonnenrain 18, 79589 Binzen, DE [DE, DE], for US only;
       MEIER, Hans-Rudolf, Muespacherstrasse 74, CH-4055 Basel, CH [CH, CH],
       for US only
       CIBA SPECIALTY CHEMICALS HOLDING INC., Patent Department, Klybeckstrasse
AG
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       English
LAF
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       WO 2004072168
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       RW (OAPI):
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       WO 2004-EP50095
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                               20030214
       EP 2003-03103835.9
                               20031016
       C08K005-20
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ICS
       C08K005-00
     ANSWER 5 OF 11 USPATFULL on STN
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       2005:203498 USPATFULL
AN
       Production of polyoxymethylene and suitable catalysts
TI
       Gortz, Hans-Helmut, Freinshein, GERMANY, FEDERAL REPUBLIC OF
IN
       Luinstra, Gerrit, Mannheim, GERMANY, FEDERAL REPUBLIC OF
       Forster, Monika, Muhltal, GERMANY, FEDERAL REPUBLIC OF
       Baumann, Andreas, Nurtingen, GERMANY, FEDERAL REPUBLIC OF
       Lindner, Ekkehard, Tubingen, GERMANY, FEDERAL REPUBLIC OF
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       US 2003-510475
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AΤ
       WO 2003-EP3746
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       Utility
       APPLICATION
FS
LN.CNT 618
       INCLM: 528/425.000
INCL
NCL
       NCLM: 528/425.000
IC
       [7]
       ICM: C08G065-34
CAS INDEXING IS AVAILABLE FOR THIS PATENT.
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     ANSWER 6 OF 11 USPATFULL on STN
AN
       2005:196141 USPATFULL
       Lithographic printing plate precursor and lithographic printing method
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       Inno, Toshifumi, Haibara-gun, JAPAN
       Oshima, Yasuhito, Haibara-gun, JAPAN
       Kakino, Ryuki, Haibara-gun, JAPAN
       Fuji Photo Film Co., Ltd. (non-U.S. corporation)
PA
PI
       US 2005170282
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                                20050804
ΑI
       US 2005-38139
                          A1
                                20050121 (11)
PRAI
       JP 2004-15723
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       JP 2004-86566
                            20040324
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       Utility
FS
       APPLICATION
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IC
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       ICM: G03C001-76
CAS INDEXING IS AVAILABLE FOR THIS PATENT.
     ANSWER 7 OF 11 USPATFULL on STN
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AN
       2001:163300 USPATFULL
       Addition-crosslinking compositions which give heat-stable silicone
TТ
       rubber
IN
       Achenbach, Frank, Simbach a. Inn, Germany, Federal Republic of
       Barthel, Herbert, Emmerting, Germany, Federal Republic of
       Wacker-Chemie GmbH, Munchen, Germany, Federal Republic of (non-U.S.
PA
       corporation)
                                20010925
DТ
       US 6294635
                          B1
AΤ
       US 1995-381809
                                19950201 (8)
PRAI
       DE 1994-4405245
                            19940218
DΤ
       Utility
FS
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LN.CNT 1143
INCL
       INCLM: 528/015.000
       INCLS: 524/403.000; 525/474.000; 525/475.000
NCL
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EXF
       524/403; 528/15; 525/474; 525/475
CAS INDEXING IS AVAILABLE FOR THIS PATENT.
     ANSWER 8 OF 11 USPATFULL on STN
L3
AN
       2000:102371 USPATFULL
TТ
       Curable resin and resin composition comprising the same
ÍΝ
       Watanabe, Tomonari, Yamato, Japan
       Natori, Itaru, Yokohama, Japan
       Asahi Kasei Kogyo Kabushiki Kaisha, Osaka, Japan (non-U.S. corporation)
PA
       US 6100339
PΤ
                                20000808
                  19960530
       WO 9616091
AΙ
       US 1997-836757 .
                                19970521 (8)
       WO 1995-JP2375
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                                          PCT 371 date
                                19970521
                                19970521
                                          PCT 102(e) date
PRAI
       JP 1994-286899
                            19941121
       Utility
DT
FS
       Granted
LN.CNT 3495
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       INCLS: 525/098.000; 525/102.000; 525/105.000; 525/106.000; 525/123.000;
              525/194.232; 525/297.000; 525/310.000; 525/314.000; 525/332.100;
              525/332.800; 525/332.900; 525/338.000; 525/342.000; 525/350.000;
              525/353.000; 525/375.000; 525/376.000; 525/379.000; 525/385.000;
              525/386.000; 524/554.000
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525/353.000; 525/375.000; 525/376.000; 525/379.000; 525/385.000;
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IC
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       ICM: C08L053-02
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EXF
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       525/342; 525/350; 525/353; 525/232; 525/338; 525/375; 525/376; 525/379;
       525/385; 525/386; 525/98; 525/102; 525/105; 525/106; 525/123; 524/554
CAS INDEXING IS AVAILABLE FOR THIS PATENT.
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AN
       1999:34093 USPATFULL
TI
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IN
       Natori, Itaru, Yokohama, Japan
       Imaizumi, Kimio, Kiyose, Japan
       Kato, Kiyoo, Kawasaki, Japan
PA
       Asahi Kasei Kogyo Kabushiki Kaisha, Osaka, Japan (non-U.S. corporation)
PΙ
       US 5883192
                                19990316
       WO 9521217 19950810
                                19960610 (8)
       US 1996-663175
AΙ
       WO 1994-JP1970
                                19941121
                                          PCT 371 date
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                                19960610
PRAI
       JP 1994-10567
                           19940201
DT
       Utility
FS
       Granted
LN.CNT 3226
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       INCLS: 525/096.000; 525/099.000; 525/211.000; 525/216.000
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EXF
       525/211; 525/216; 525/96; 525/98; 525/99
CAS INDEXING IS AVAILABLE FOR THIS PATENT.
L3 .
     ANSWER 10 OF 11 USPATFULL on STN
AN
       91:56827 USPATFULL
TΤ
       Method of metalizing a surface using a mixture of olefin and
       dibenzalacetone palladium complex
IN
       Finter, Jurgen, Freiburg, Germany, Federal Republic of
PΑ
       Ciba-Geigy Corporation, Ardsley, NY, United States (U.S. corporation)
PΤ
       US 5032488
                                19910716
AΤ
       US 1988-165448
                                19880301 (7)
RLT
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PRAI
       CH 1985-3645
                           19850823
DТ
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FS
LN.CNT 582
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       INCLS: 430/281.000; 430/283.000; 430/284.000; 430/285.000; 430/324.000;
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              522/129.000; 522/152.000
IC
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EXF
       430/285; 522/34; 522/66; 522/152
CAS INDEXING IS AVAILABLE FOR THIS PATENT.
     ANSWER 11 OF 11 USPATFULL on STN
L3
AN
       85:13443 USPATFULL
TI
       Glycolaldehyde process
IN
       Auvil, Steven R., Macungie, PA, United States
```

525/332.800; 525/332.900; 525/338.000; 525/342.000; 525/350.000;

Mills, Patrick L., Creve Coeur, MO, United States PA Monsanto Company, St. Louis, MO, United States (U.S. corporation) ΡI US 4503260 19850305 ΑI US 1983-504001 19830613 (6) DT Utility FS Granted LN.CNT 822 INCL INCLM: 568/462.000 INCLS: 568/420.000; 568/458.000 NCL NCLM: 568/462.000 NCLS: 568/420.000; 568/458.000 [3] IC ICM: C07C045-49 568/458; 568/462; 568/420; 568/862 EXF

CAS INDEXING IS AVAILABLE FOR THIS PATENT.

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